				Docket Number (Optional) 16791 (03006)		Application Number Unassigned				
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OD		5,663,507	09/02/97	Westervelt, et al.						
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		OTHE	R DOCUMENTS	(Including)	Author, Title, Date, Pertinen	it Pages, Etc.)				
08		T. Zhou, et al.; "Extraordinary magnetoresistance in externally shunted van der Pauw plates"; Applied Physics Letters; Vol. 78; No. 5; pp. 667-69; (2001)								
00		S.A. Solin, et al.; "Nonmagnetic semiconductors as read-head sensors for ultra-high-density magnetic recording:, Applied Physics Letters; Vol. 80; No. 21; pp. 4012-14; (2002)								
00)		A.C.H. Rowe, et al.; "A uniaxial tensile stress apparatus for temperature-dependent magnetotransport and optical studies of thin films"; Review of Scientific Instruments; Vol. 73; No. 12; pp. 4270-76; (2002)								
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EXAMINER DATA DANS DATE CONSIDERED 10/21/04										
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not										

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considered. Include copy of this form with next communication to applicant.

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		OTHE	R DOCUMENTS ((Including A	uthor, Title, Date, Pertir	nent Pages, Etc.)				
OB		C.A. Mead, et al.; "Fermi Level Position at Metal-Semiconductor Interfaces"; Physical Review; Vol. 134; No. 3A; pp. A713-16; (1964)								
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		ОТНЕ	R DOCUMENTS ((Including A	uthor, Title, Date, Per	tinent Pages, Etc.)	<u> </u>				
08		Adhesives List printed from www.tokyosokki.co.jp/e/product; on 6/27/2003									
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